

STX790A

Medium Current, High Performance, Low Voltage PNP Transistor

General features

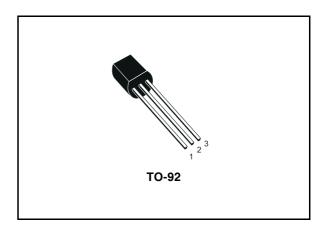
- Very low Collector to Emitter saturation voltage
- D.C. Current gain, h_{FE} >100
- 3A continuous collector current
- 40V breakdown voltage (V_{(BR)CER})
- In compliance with the 2002/93/EC European Directive

Description

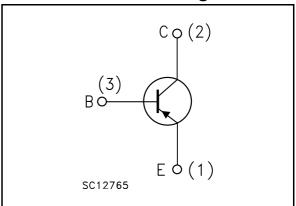
The device in manufactured in low voltage PNP Planar Technology by using a "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

Applications

- Power management in portable equipment
- Voltage regulation in bias supply circuits
- Switching regulator in battery charger applications
- Heavy load driver



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
STX790A	X790A	TO-92	Bulk
STX790A-AP	X790A	TO-92 AP	Ammopack

Contents

1	Elec	trical ratings
2	Elec	trical characteristics
	2.1	Electrical characteristics (curves)
	2.2	Test circuits 6
3	Pack	age mechanical data
4	Revi	sion history 1(

STX790A Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-40	V
V _{CER}	Collector-emitter voltage ($R_{BE} = 47\Omega$)	-40	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-30	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
I _C	Collector current	-3	Α
I _{CM}	Collector peak current (t _P < 5ms)	-6	Α
P _{tot}	Total dissipation at T _c = 25°C	0.9	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	44.6	°C/W
R _{thj-amb}	Thermal resistance junction-amb max	139	°C/W

5/

Electrical characteristics STX790A

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

Symbol	Parameter	Test Co	nditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	$V_{CB} = -30V$ $V_{CB} = -30V$;	T _C = 100°C			-10 100	μ Α μ Α
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -4V				-10	μА
V _{(BR)CEO} (2)	Collector-emitter breakdown voltage (I _B =0)	I _C = -10mA		-30			V
V _{(BR)CER} (2)	Collector-emitter breakdown voltage (R _{BE} = 47Ω)	I _C = -10mA		-40			V
V _{(BR)CBO}	Collector-base breakdown voltage (I _E =0)	I _C = -100μA		-40			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C =0)	I _E = -100μA		-5			V
V _{CE(sat)} (2)	Collector-emitter	$I_C = -0.5A$	$I_B = -5mA$			-0.15	V
VCE(sat)	saturation voltage	$I_C = -1.2A$	$I_B = -20 \text{mA}$			-0.25	V
		I _C = -2A	$I_B = -20 \text{mA}$			-0.5	V
		_	$I_B = -100 \text{mA}$			-0.7	V
			$I_B = -100 \text{mA}$			-0.9	V
		$T_J = 100^{\circ}C$					
V _{BE(sat)} (2)	Base-emitter saturation voltage	I _C = -1A	I _B = -10mA		-0.8	-1	٧
V _{BE(on)} (2)	Base-emitter on voltage	I _C = -1A	V _{CE} = -2V		-0.8	-1	V
		$I_C = -10mA$	$V_{CE} = -2V$	100	200	400	
		I _C = -500mA	$V_{CE} = -2V$	100	200	400	
h _{FE} ⁽²⁾	DC current gain	I _C = -1A	$V_{CE} = -2V$	100			
		I _C = -2A	$V_{CE} = -1V$	100	160		
		$I_C = -3A$	$V_{CE} = -1V$	90	130		

4/11

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
f _t	Transition frequency	$I_C = -50 \text{mA}$ $V_{CE} = -5V$ f = 50 MHz		100		MHz
t _d t _r t _s	Resistive load Delay time Rise time Storage time Fall time	$I_{C} = -3A$ $V_{CC} = -20V$ $I_{B1} = -I_{B2} = -60mA$ (see figure 7)		180 160 250 80	220 210 300 100	ns ns ns

Note (2) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

2.1 Electrical characteristics (curves)

Figure 1. DC current gain

Figure 2. DC current gain

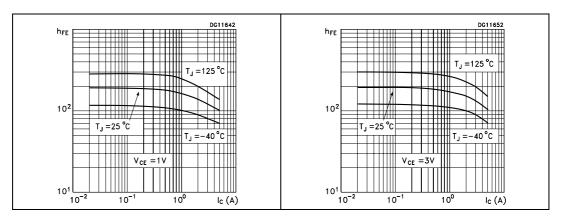
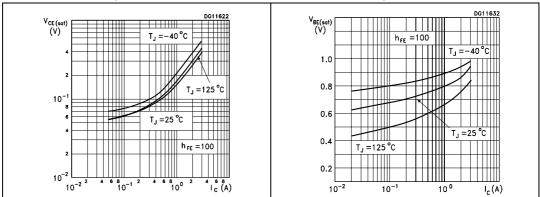
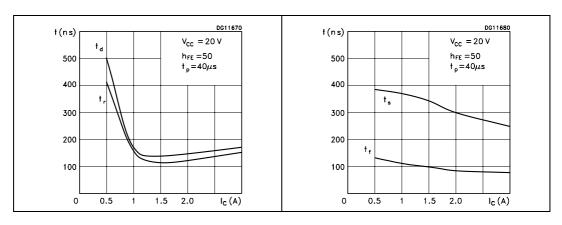


Figure 3. Collector-emitter saturation Figure 4. Base-emitter saturation voltage voltage



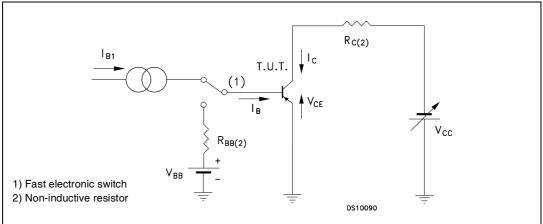
Electrical characteristics STX790A

Figure 5. Switching time resistive load Figure 6. Switching time resistive load



2.2 Test circuits

Figure 7. Resistive load switching test circuit



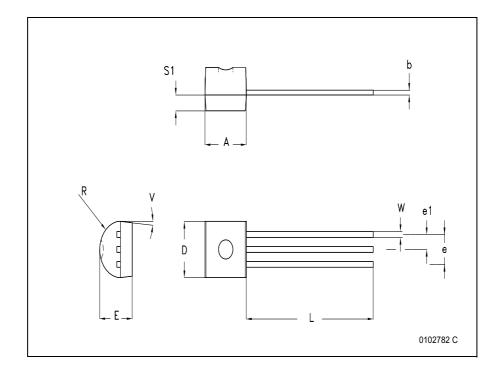
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

5/

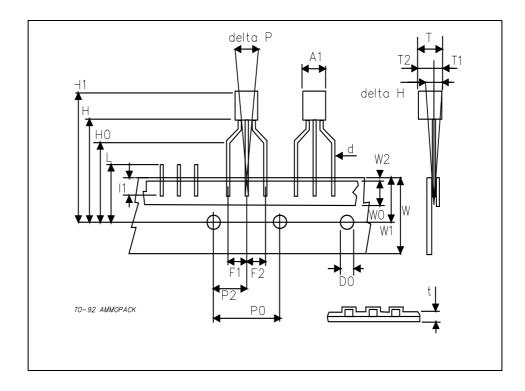
TO-92 BULK SHIPMENT MECHANICAL DATA

DIM		mm.	
DIM.	MIN.	ТҮР	MAX.
Α	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
е	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5 ^O	



TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA

DIM.		mm.			
DIN.	MIN.	TYP	MAX.		
A1			4.80		
T			3.80		
T1			1.60		
T2			2.30		
d			0.48		
P0	12.50	12.70	12.90		
P2	5.65	6.35	7.05		
F1,F2	2.44	2.54	2.94		
delta H	-2.00		2.00		
W	17.50	18.00	19.00		
W0	5.70	6.00	6.30		
W1	8.50	9.00	9.25		
W2			0.50		
Н	18.50		20.50		
H0	15.50	16.00	16.50		
H1			25.00		
D0	3.80	4.00	4.20		
t			0.90		
L			11.00		
I1	3.00				
delta P	-1.00		1.00		



57

Revision history STX790A

4 Revision history

Table 4. Revision history

Date	Revision	Changes
24-Mar-2003	1	Initial release.
29-Mar-2006	2	New template.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT DESIGNED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

